Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.400 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
То-64
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
4.70 amperes forward current, total rms nanoamperes
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnpnp
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Specification Data:
80131-release3249d professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Filg:
A110a0